

Tuesday 18 September

15:00

Session 4 R/D and device and detector simulation Session | Location: Seogwipo KAL Hotel, Jeju, Korea | Convener: Hans-Günther Moser 15:00-15:30 Strip Technology and HVMPAS Speaker Dr Ivan Peric 15:30-16:00 Coffee Break 16:00-16:30 "Why p-type is Better than n-type" or Electric Field in Heavily Irradiated Silicon **Detectors** Speaker Gregor Kramberger 16:30-17:00 ATLAS FEI4 ASIC Speaker Lea Michaela Caminada 17:00-17:30 "Scribing-Cleaving-Passivation" for High Energy Physics Silicon Sensors Speaker Marc Christophersen 18:00